### Changes in cooling due to recent developments in SimCool code

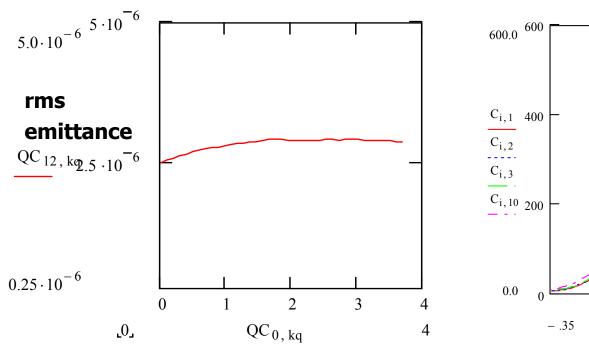
Major changes during November'2003-February'2004:

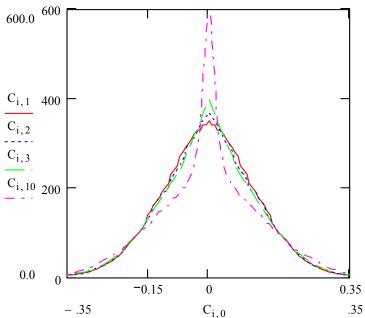
- 1. Synchrotron motion was added.
- 2. IBS diffusion coefficients were adjusted, dispersion was included in transverse IBS growth rates.
- 3. Calculation of electron density for both Gaussian and uniform beam with corresponding ratio of electron bunch length/ ion bunch length.

Had some (insignificant) effect on cooling of beam core.



# Old parameters, SimCool results with changes done November'03 - February'04





Old (2001-2003) baseline parameters:  $\varepsilon_t$ =30\*10<sup>-6</sup>, B=1T,  $\sigma_{se}$ = $\sigma_{si}$ , L=30 m



1. Old parameter were unsufficient to produce significant reduction of rms or 95% emittances, as well as rms bunch length.

2. But significant luminosity gain could be still achieved due to effective cooling of beam core.

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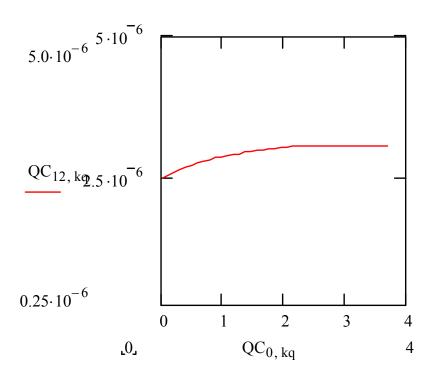
**Presented at MAC'04** 

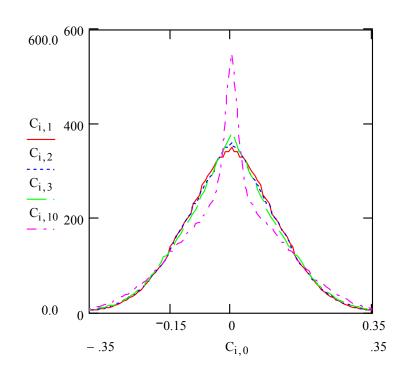
#### Additional changes in the code: March-April' 2004

These changes are small by itself, but for our region of small cooling logarithm they make a big difference.

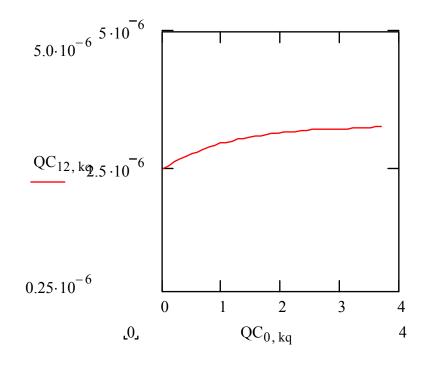


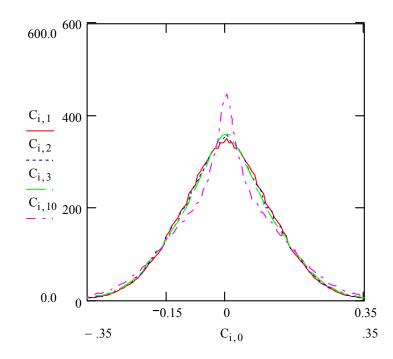
# 1. Maximum impact parameter is decreased by taken into account plasma frequency (electron density) in calculations



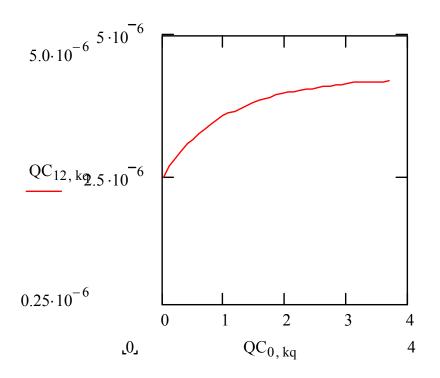


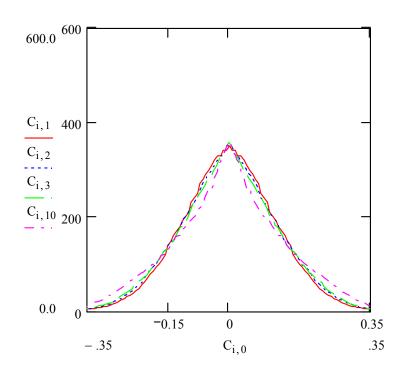
# 2. Additional factor sqrt[2] (missing before) was added in calculation of transverse velocity of electrons.





### 3. New calculation of IBS for distribution with a cold core

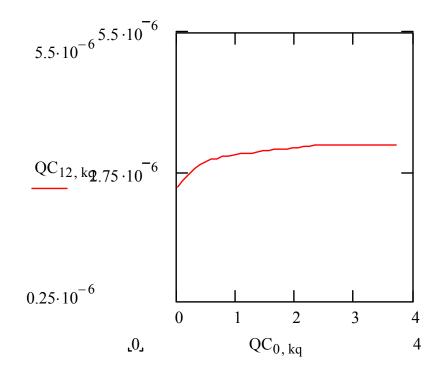


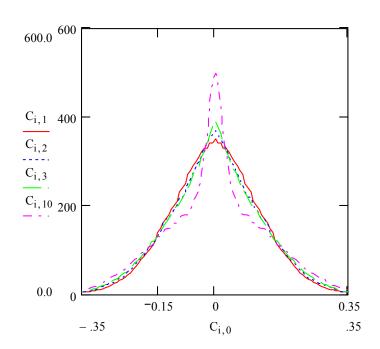


Net result of changes 1+2+3 – no rapid cooling with old parameters – need some optimization of parameters to get cooling back (next slide)



#### Example: q increased to 20nC, B=2T

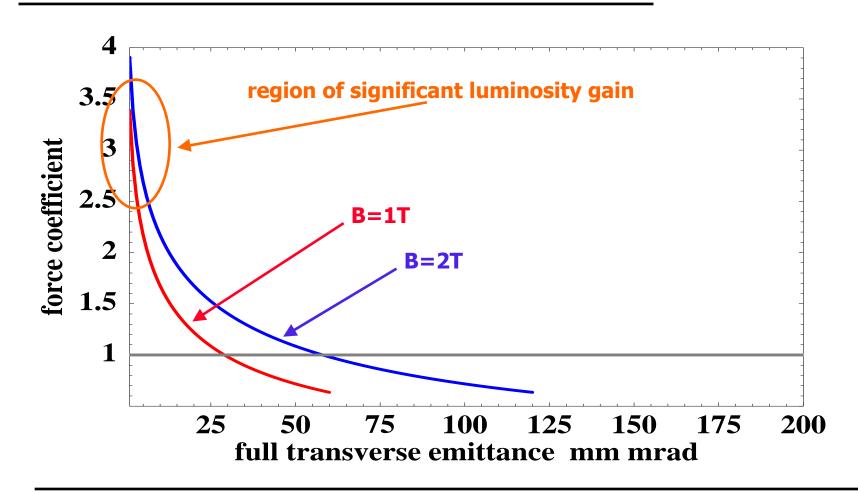




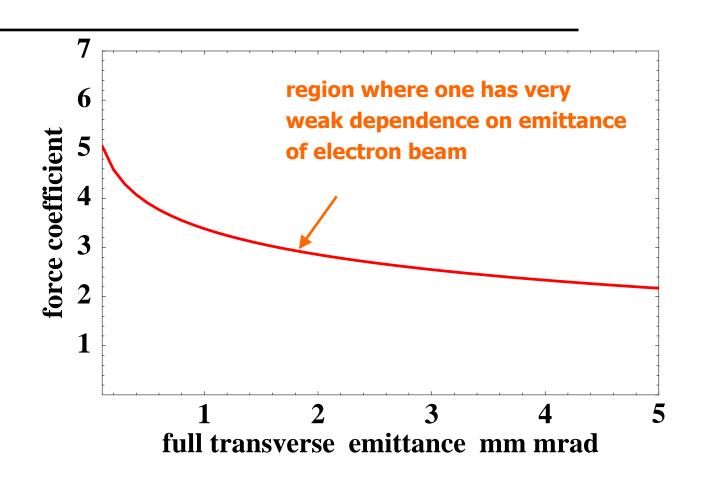
Cooling is back – in the assumption that small emittance of electron beam can be achieved (see slides on "requirements on beam emittance")



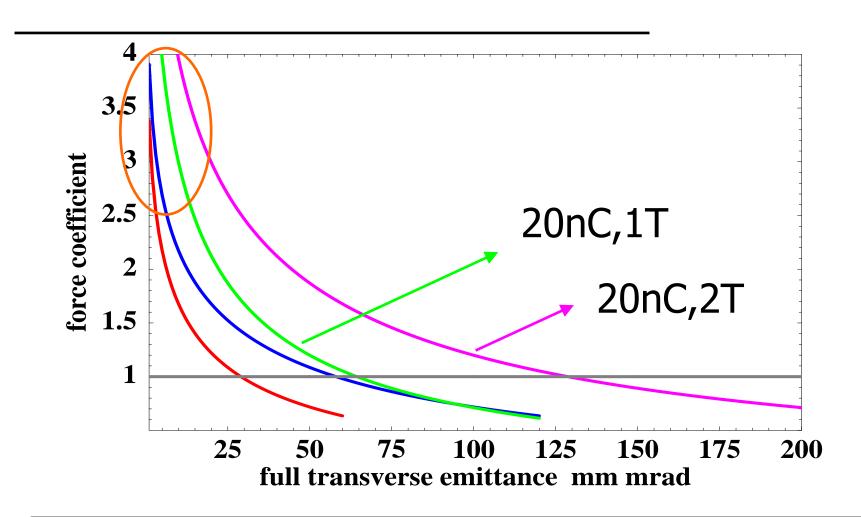
#### q=10 nC



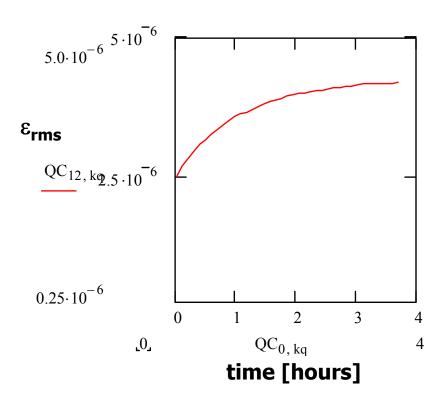
#### Large cooling Log region (very small emittances)

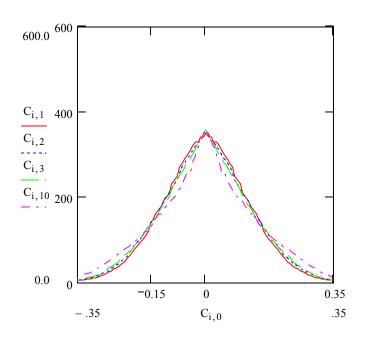


#### Charge 10 & 20 nC

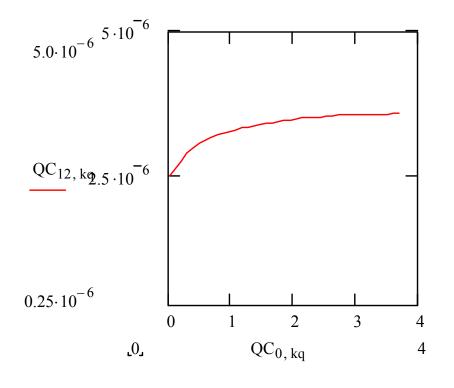


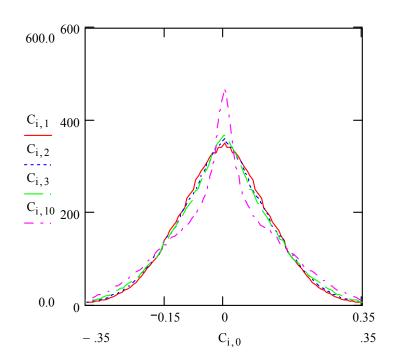
#### 10 nC, $ε_x$ =15e-6, $ε_t$ =30e-6 (B=2T)



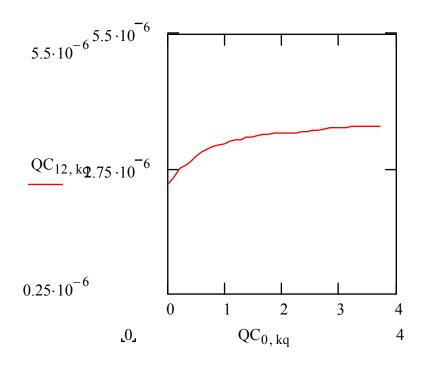


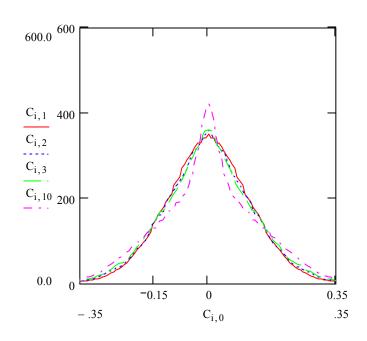
#### 10 nC, $ε_x$ =5e-6, $ε_t$ =10e-6 (B=2T)



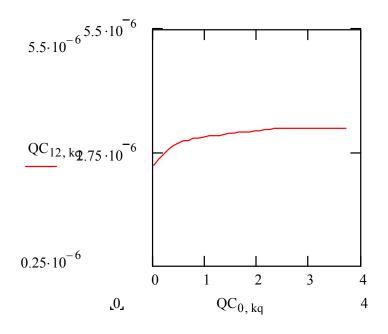


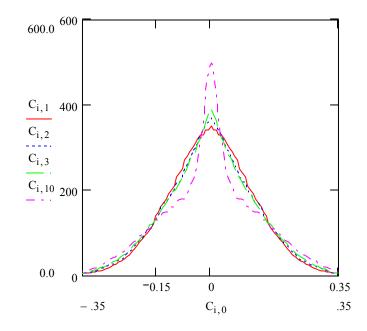
#### 20 nC, $\varepsilon_x$ =25e-6, $\varepsilon_t$ =50e-6 (B=2T)



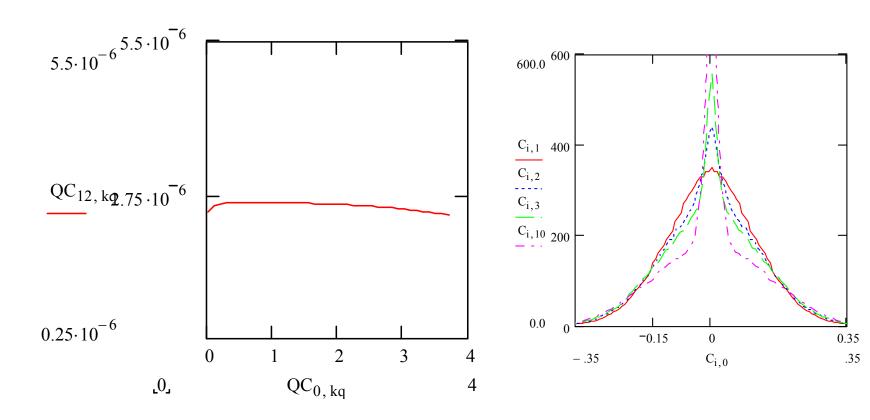


#### 20nC, $ε_x$ =15e-6, $ε_t$ =30e-6 (B=2T)

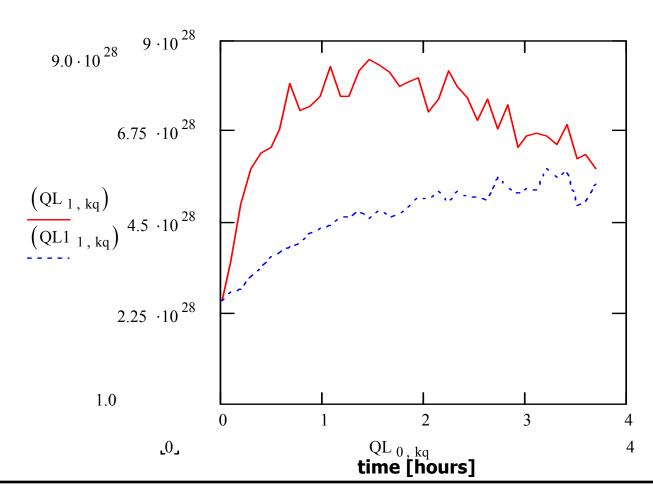




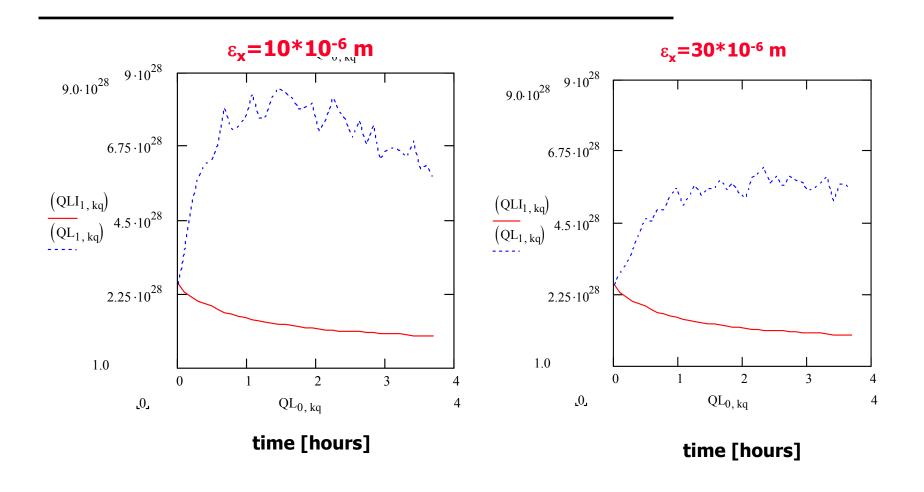
#### q=20nC, B=4T, $\varepsilon_x$ =10\*10-6



# B=4T , $\epsilon_x$ =10\*10<sup>-6</sup> – luminosity increase due to optimization of electron beam parameters



### B=5 T – luminosity (350 bunches) increase for various emittances of electron beam



Requirements on emittance of electron beam needed to achieve desired luminosity increase (for B=2, 4 and 5 T) with q=20nC

